

Features

• Collector Current: I_C=0.6A

Power Dissipation of 300mw

1. BASE

2. EMTTER

3. COLLECTOR



Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)	
HMMBT5551T	SOT-523	G1	3000	

SOT-523



Maximum Ratings (Ta=25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Collector-Base Voltage	V _{CBO}	180	V
Collector-Emitter Voltage	V _{CEO}	160	V
Emitter-Base Voltage	V _{EBO}	6	V
Collector Current	I _c	600	mA
Collector Power Dissipation	P _c	300	mW
Thermal Resistance From Junction To Ambient	R _{eJA}	416	°C/W
Junction Temperature	T _j	150	℃
Storage Temperature	T _{stg}	- 55∼+150	°C

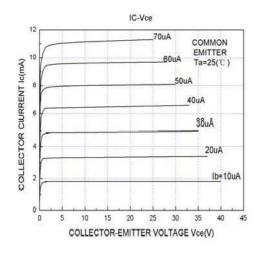
Electrical Characteristics (Ta =25°C unless otherwise specified)

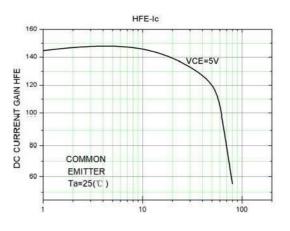
Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C =100μA, I _E =0	180			V
Collector-emitter breakdown voltage	V _{(BR)CEO} *	I _C =1mA, I _B =0	160			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	I _E =10μA, I _C =0	6			V
Collector cut-off current	I _{CBO}	V _{CB} =120V, I _E =0			50	nA
Emitter cut-off current	I _{EBO}	V _{EB} =4V, I _C =0			50	nA
DC current gain	h _{FE(1)} *	V _{CE} =5V, I _C =1mA	80			
	h _{FE(2)} *	V _{CE} =5V, I _C =10mA	100		300	
	h _{FE(3)} *	V _{CE} =5V, I _C =50mA	50			
Collector orgittor activistics well-	V _{CE(sat)1} *	I _C =10mA, I _B =1mA			0.15	V
Collector-emitter saturation voltage	$V_{\text{CE(sat)2}}^{*}$	I _C =50mA, I _B =5mA			0.2	V
Base emitter esturation voltage	V _{BE(sat)1} *	I _C =10mA, I _B =1mA			1	V
Base-emitter saturation voltage	V _{BE(sat)2} *	I _C =50mA, I _B =5mA			1	V
Transition frequency	f⊤	V _{CE} =10V,I _C =10mA, f=100MHz	100		300	MHz
Collector output capacitance	C _{ob}	V _{CB} =10V, I _E =0, f=1MHz			6	pF

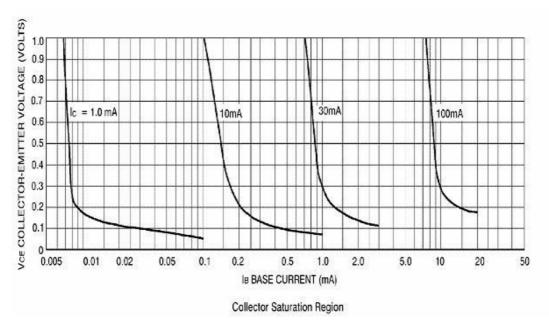
^{*}Pulse test: pulse width ≤300µs, duty cycle≤ 2.0%.



Typical Characteristics

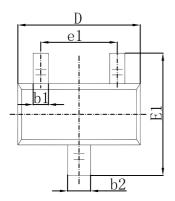


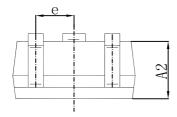


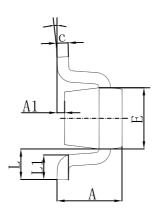




SOT-523 Package Information

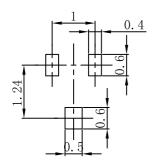






Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
Α	0.700	0.900	0.028	0.035	
A1	0.000	0.100	0.000	0.004	
A2	0.700	0.800	0.028	0.031	
b1	0.150	0.250	0.006	0.010	
b2	0.250	0.350	0.010	0.014	
С	0.100	0.200	0.004	0.008	
D	1.500	1.700	0.059	0.067	
E	0.700	0.900	0.028	0.035	
E1	1.450	1.750	0.057	0.069	
е	0.500 TYP.		0.020 TYP.		
e1	0.900	1.100	0.035	0.043	
Ĺ	0.400 REF.		0.016 REF.		
L1	0.260	0.460	0.010	0.018	
θ	0°	8°	0°	8°	

SOT-523 Suggested Pad Layout



Note:

- 1. Controlling dimension: in millimeters.
- 2.General tolerance:±0.05mm.
- 3. The pad layout is for reference purposes only.



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